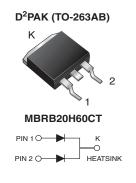
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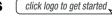
# **Dual Common Cathode Schottky Rectifier**

High Barrier Technology for Improved High Temperature Performance



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### **DESIGN SUPPORT TOOLS**





PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 10 A			
V <sub>RRM</sub>	60 V			
I <sub>FSM</sub>	150 A			
V <sub>F</sub>	0.61 V			
I <sub>R</sub>	100 µA			
T <sub>J</sub> max.	175 °C			
Package	D <sup>2</sup> PAK (TO-263AB)			
Circuit configuration	ion Common cathode			

## FEATURES

- Power pack
- Guardring for overvoltage protection
- Low power loss, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245  $^{\circ}\mathrm{C}$
- AEC-Q101 qualified available - Automotive ordering code: base P/NHE3\_A
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

## **MECHANICAL DATA**

Case: D<sup>2</sup>PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/NHE3\_X - RoHS-compliant, AEC-Q101 qualified ("\_X" denotes revision code, e.g. A, B, ...)

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102 HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

<b>MAXIMUM RATINGS</b> ( $T_C = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER			MBRB20H60CT	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	60		
Working peak reverse voltage		V <sub>RWM</sub>	60	V	
Maximum DC blocking voltage		V <sub>DC</sub> 60		7	
Maximum average forward rectified current (fig. 1)	total device		20	Α	
	per diode	I <sub>F(AV)</sub>	10	A	
Non-repetitive avalanche energy per diode at 25 °C, $I_{AS}$ = 4 A, L = 10 mH			80	mJ	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	150	A	
Peak repetitive reverse surge current per diode at $t_p = 2.0 \ \mu s$ , 1 kHz		I <sub>RRM</sub>	0.5		
Peak non-repetitive reverse energy (8/20 µs waveform)		E <sub>RSM</sub>	10	mJ	
Electrostatic discharge capacitor voltage Human body model: C = 100 pF, R = $1.5 \text{ k}\Omega$		V <sub>C</sub>	25	kV	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-65 to +175	°C	



COMPLIANT



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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_c = 25$ °C unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		MBRB20H60CT		UNIT	
	STINIBUL			TYP.	MAX.	UNIT	
Maximum instantaneous forward voltage per diode	V <sub>F</sub> <sup>(1)</sup>	I <sub>F</sub> = 10 A	T <sub>C</sub> = 25 °C	-	0.71	v	
		I <sub>F</sub> = 10 A	T <sub>C</sub> = 125 °C	0.57	0.61		
		VF ()	I <sub>F</sub> = 20 A	T <sub>C</sub> = 25 °C	-	0.85	v
		I <sub>F</sub> = 20 A	T <sub>C</sub> = 125 °C	0.68	0.71		
Maximum reverse current per diode	I <sub>R</sub> <sup>(2)</sup>	I <sub>B</sub> <sup>(2)</sup> Rated V <sub>B</sub>	T <sub>J</sub> = 25 °C	-	100	μA	
		'R `-'	naleu v <sub>R</sub>	T <sub>J</sub> = 125 °C	2.0	12	mA

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

 $^{(2)}$  Pulse test: pulse width  $\leq 40\ ms$ 

<b>THERMAL CHARACTERISTICS</b> ( $T_C = 25$ °C unless otherwise noted)					
PARAMETER	SYMBOL	MBRB20H60CT	UNIT		
Typical resistance, junction to case per diode	$R_{ extsf{ heta}JC}$	2.0	°C/W		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	MBRB20H60CTHE3_A/P (1)	1.35	Р	50/tube	Tube	
TO-263AB	MBRB20H60CTHE3_A/I <sup>(1)</sup>	1.35	I	800/reel	Tape and reel	

Note

(1) AEC-Q101 qualified



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## **RATINGS AND CHARACTERISTICS CURVES** ( $T_C = 25$ °C unless otherwise noted)

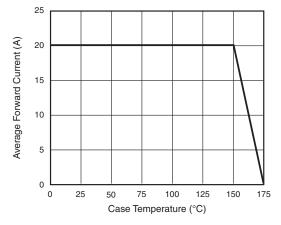


Fig. 1 - Forward Current Derating Curve (Total)

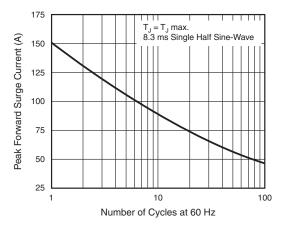


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

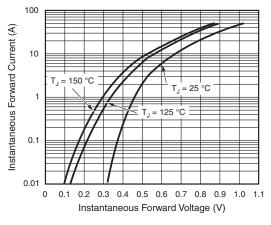


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

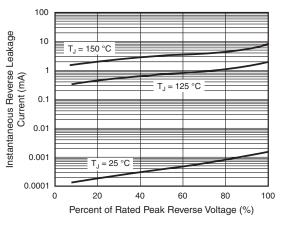


Fig. 4 - Typical Reverse Characteristics Per Diode

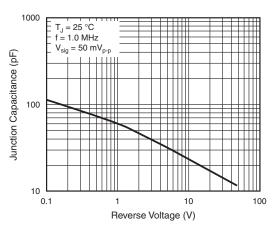


Fig. 5 - Typical Junction Capacitance Per Diode

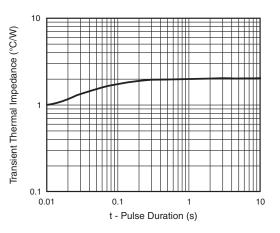


Fig. 6 - Typical Transient Thermal Impedance Per Diode

Revision: 13-Jun-2018

3

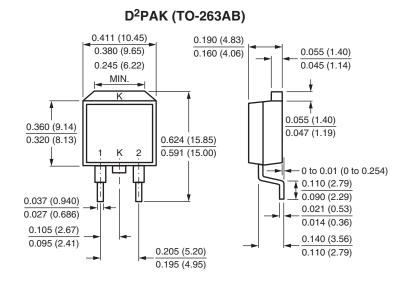
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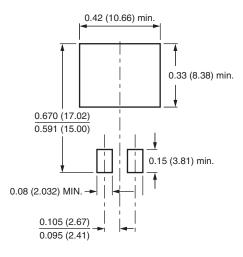




## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



**Mounting Pad Layout** 





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